



Future Normal in Semiconductor

2025-02-13(목), 10:55-12:40

좌장: 추후업데이트 예정

C. Material Growth & Characterization 분과

[TF2-C] Characterization of Oxide Heterostructures for Advanced Applications

<p>초청 TF2-C-1 10:55-11:25</p>	<p>In-situ/Operando Analysis of Topotactic Phase Transition in Complex Oxides Dooyong Lee Department of Physics Education, Kyungpook National University</p>
<p>TF2-C-2 11:25-11:40</p>	<p>Spatially-Resolved Mapping of Ferroelectric Phase Transition in Two-Dimensional Halide Perovskite Tae Hyun Jung, Yunseung Kuk, Sang Woo Lee, Sung Bin Bae, June Hee Shin, Kang Min Ok, and Sang Mo Yang Sogang University</p>
<p>TF2-C-3 11:40-11:55</p>	<p>Advanced spectroscopic methods for probing in-gap defect states in amorphous SiNx for charge trap memory applications Minseon Gu¹, Hanyeol Ahn¹, Moonsup Han¹, Eunjip Choi¹, Hyun Don Kim^{1,2}, Junghyun Beak^{1,2}, Hyeongjoon Lim^{1,2}, Jaemo Jung^{1,2}, Jaehyeon Park^{1,2}, Kyu-Myung Lee³, Jinwoo Byun⁴, Gukhyon Yon⁴, Jwa Soon Kim⁵, HaeJoon Hahm⁵, Soobang Kim⁵, Won Ja Min⁵, Moon Seop Hyun⁶, Yun Chang Park⁶, Gyungtae Kim⁶, Yongsup Park^{3,7}, and Young Jun Chang^{1,8} ¹Department of Physics, University of Seoul, ²Department of Smart Cities, University of Seoul, ³Department Physics and Research Institute of Basic Sciences, Kyung Hee University, ⁴Advanced Process Development Team, Semiconductor R&D Center, Samsung Samsung Electronics, ⁵HB Solution, ⁶NNFC, ⁷Department of Information Display, Kyung Hee University, ⁸Department of Intelligent Semiconductor Engineering, University of Seoul</p>
<p>TF2-C-4 11:55-12:10</p>	<p>DFT Study on Schottky Barrier Heights in M₆S₂ with Direct and van der Waals Contacts Hyunijn Lee¹, Jae-Hyun Lee², Soheil Ghods^{1,2}, Keun Heo^{1,3}, Jinuk Kwon³, Yoon Kyeong Lee^{4,5}, and Taehun Lee^{4,6} ¹School of Semiconductor and Chemical Engineering, Semiconductor Physics Research Center, Jeonbuk National University, ²Department of Materials Science and Engineering and Department of Energy Systems Research, Ajou University,</p>



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TF2-C-5 12:10-12:25	Impact of Bulk Traps on Polarization Switching in a-In₂Se₃ Ferroelectric Semiconductor FETs by Frequency Dispersive C-V Characteristics Minah Park ¹ , Sieun Lee ¹ , Jaewook Yoo ¹ , Seohyeon Park ¹ , Hongseung Lee ¹ , Hyeonjun Song ¹ , Soyeon Kim ¹ , Seongbin Lim ¹ , Sojin Jung ¹ , TaeWan Kim ³ , Peide D. Ye ² , and Hagyoul Bae ¹ ¹ Jeonbuk National University, ² Purdue University, ³ University of Seoul
TF2-C-6 12:25-12:40	Temperature-dependent {111}-Texture Transfer to Hf_{0.5}Zr_{0.5}O₂ Films from (111)-textured TiN Electrode and Its Impact on Ferroelectricity Dong Hee Han ¹ , Seung Yeon Kim ² , Younghwan Lee ³ , Young Yong Kim ⁴ , Woojin Jeon ² , and Min Hyuk Park ^{1,5} ¹ Seoul National University, ² Kyung Hee University, ³ Chonnam National University, ⁴ PAL, POSTECH, ⁵ Institute of Engineering Research, Seoul National University